

XC6229 Series

ETR03062-005b

300mA Ultra Small High Speed LDO Regulator, Built-in Inrush Current Protection

■ GENERAL DESCRIPTION

The XC6229 series is a high speed LDO regulator that features high accurate, low noise, high ripple rejection, low dropout and low power consumption. Housed in the ultra-small LGA-4B01 (0.75 x 0.75, h=0.3mm MAX.) package, the XC6229 is ideal for space-saving design. The XC6229 consists of a voltage reference, an error amplifier, a driver transistor, a current limiter, a phase compensation circuit, a thermal shutdown circuit and an inrush current protection circuit.

The CE function enables the circuit to be in stand-by mode by inputting low level signal. In the stand-by mode, the series enables the electric charge at the output capacitor C_L to be discharged via the internal switch, and as a result the V_{OUT} pin quickly returns to the V_{SS} level. The output stabilization capacitor C_L is also compatible with low ESR ceramic capacitors.

The output voltage is selectable in 0.05V increments within the range of 1.2V to 4.0V which fixed by laser trimming technologies. The over current protection circuit and the thermal shutdown circuit are built-in. These two protection circuits will operate when the output current reaches current limit level or the junction temperature reaches temperature limit level.

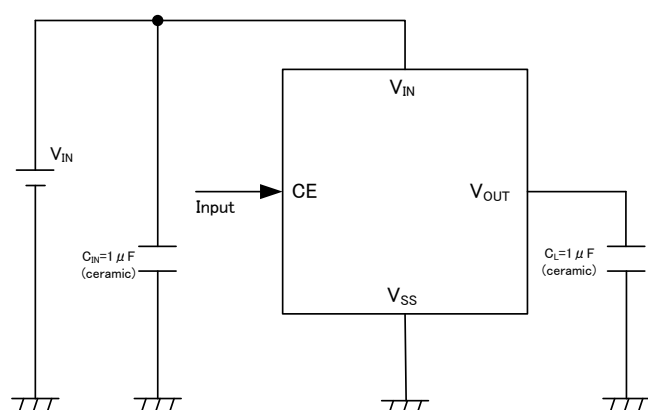
■ APPLICATIONS

- Mobile devices / terminals
- Wireless LAN
- Modules (Wireless, Camera, etc.)
- Smart Phones / Mobile phones

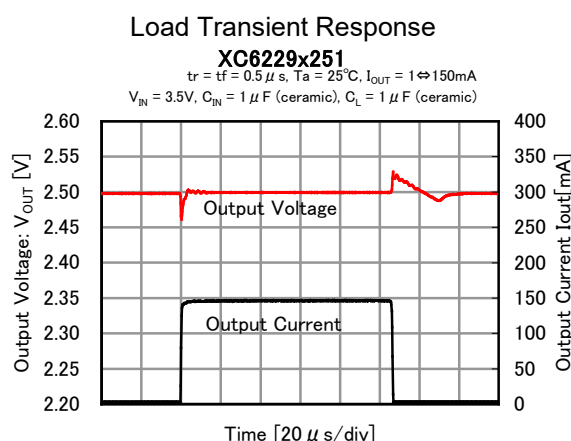
■ FEATURES

Maximum Output Current	: 300mA
Input Voltage Range	: 1.6 ~ 5.5V
Output Voltages	: 2.0 ~ 4.0V (Accuracy $\pm 1\%$) 1.2 ~ 1.95V (Accuracy $\pm 20mV$) 0.05V increments
Dropout Voltage	: 80mV@ $I_{OUT}=150mA$ ($V_{OUT}=3.0V$)
Low Power Consumption	: 100 μA
Stand-by Current	: 0.01 μA
High Ripple Rejection	: 80dB@f=1kHz
Protection Circuits	: Current Limit (400mA) Thermal shutdown Protection Inrush Current Protection
Low ESR Capacitors	: $C_{IN}=1.0 \mu F$, $C_L=1.0 \mu F$
CE Function	: Active High C_L High Speed Discharge
Operating Ambient Temperature	: -40°C ~ 85°C
Small Package	: LGA-4B01 (0.75x0.75x0.3mm MAX.)
Environmentally Friendly	: EU RoHS Compliant, Pb Free

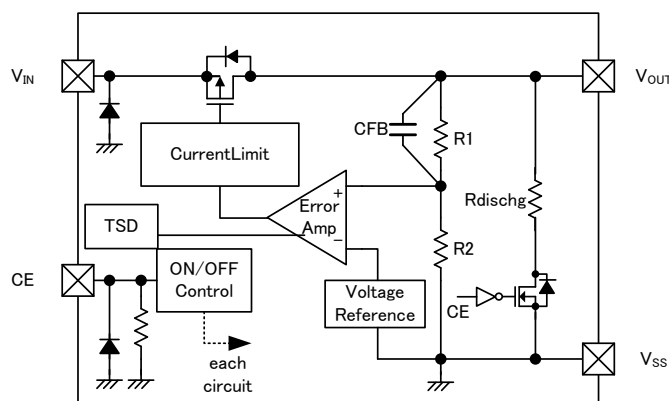
■ TYPICAL APPLICATION CIRCUIT



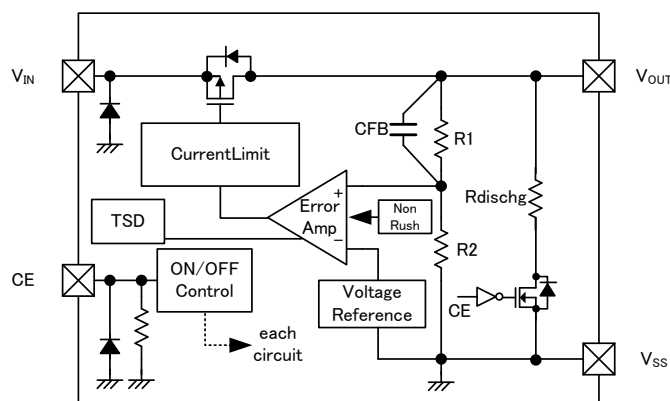
■ TYPICAL PERFORMANCE CHARACTERISTICS



BLOCK DIAGRAMS



XC6229series Type D



XC6229series Type H

* Diodes inside the circuits are ESD protection diodes and parasitic diodes.

PRODUCT CLASSIFICATION

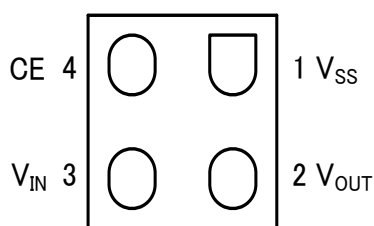
Ordering Information

XC6229①②③④⑤⑥-⑦^(*)

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION
①	Type	D	CE Active High Without Inrush Current Protection With CE Pull-down, With C _L discharge
		H	CE Active High With Inrush Current Protection With CE Pull-down, With C _L discharge
②③	Output Voltage	12 ~ 40	ex.) 2.80V → ②=2, ③=8, ④=please see down below.
④	Output Voltage (2nd decimal place)	1	±1%, In case of 2nd decimal place 0 (ex.2.80V → ④=1)
		B	±1%, In case of 2nd decimal place 5 (ex.2.85V → ④=B)
⑤⑥-⑦ ^(*)	Package (Order Unit)	1R-G	LGA-4B01 (5,000pcs /Reel)

^(*) The "-G" suffix denotes Halogen and Antimony free as well as being fully EU RoHS compliant.

■ PIN CONFIGURATION



LGA-4B01
(BOTTOM VIEW)

■ PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTIONS
LGA-4B01		
3	V _{IN}	Power Input
2	V _{OUT}	Output
1	V _{SS}	Ground
4	CE	ON/OFF Control

■ PIN FUNCTION ASSIGNMENT

CE LOGIC CONDITION	IC OPERATION
H	Operation ON
L	Operation OFF(Stand-by)
OPEN	*

* For D and H types, CE pin voltage is fixed as L level because of internal pull-down resistor.

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNITS
Input Voltage		V _{IN}	V _{SS} - 0.3 ~ V _{SS} + 7.0	V
Output Current		I _{OUT}	500 (*1)	mA
Output Voltage		V _{OUT}	V _{SS} -0.3 ~ V _{IN} + 0.3	V
CE Input Voltage		V _{CE}	V _{SS} - 0.3 ~ V _{SS} + 7.0	V
Power Dissipation	LGA-4B01	Pd	150 (IC only)	mW
			600 (40mm x 40mm standard board) (*2)	
Operating Ambient Temperature		Topr	-40 ~ 85	℃
Storage Temperature		Tsta	-55~ 125	℃

(*1) $I_{OUT} \leq Pd / (V_{IN} - V_{OUT})$

(*2) The power dissipation figure shown is PCB mounted and is for reference only.

Please refer to PACKAGING INFORMATION for the mounting condition.

ELECTRICAL CHARACTERISTICS

Ta=25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS	CIRCUITS
Output Voltage	$V_{OUT(E)}$ ^(*1)	$V_{OUT(T)} \geq 2.0V$, $V_{CE}=V_{IN}$, $I_{OUT}=10mA$	$V_{OUT(T)} \times 0.99$ ^(*2)	$V_{OUT(T)}$ ^(*2)	$V_{OUT(T)} \times 1.01$ ^(*2)	V	①
		$V_{OUT(T)} < 2.0V$, $V_{CE}=V_{IN}$, $I_{OUT}=10mA$ ^(*3)	$V_{OUT(T)} - 20mV$ ^(*2)	$V_{OUT(T)}$ ^(*2)	$V_{OUT(T)} + 20mV$ ^(*2)	V	
Maximum Output Current	I_{OUTMAX}	$V_{CE}=V_{IN}$	300	-	-	mA	①
Load Regulation	ΔV_{OUT}	$V_{CE}=V_{IN}$, $0.1mA \leq I_{OUT} \leq 300mA$	-	25	45	mV	①
Dropout Voltage	V_{dif} ^(*4)	$V_{CE}=V_{IN}$, $I_{OUT}=300mA$	-	E-1		mV	①
Supply Current	I_{SS}	$V_{CE}=V_{IN}$	-	100	220	μA	②
Stand-by Current	I_{STB}	$V_{CE}=V_{SS}$	-	0.01	0.4	μA	②
Line Regulation	$\Delta V_{OUT}/$ $(\Delta V_{IN} \cdot V_{OUT})$	$V_{OUT(T)} + 0.5V \leq V_{IN} \leq 5.5V$ $V_{CE}=V_{IN}$, $I_{OUT}=50mA$	-	0.01	0.1	%/V	①
Input Voltage	V_{IN}	-	1.6	-	5.5	V	①
Output Voltage Temperature Characteristics	$\Delta V_{OUT}/$ $(\Delta T_{opr} \cdot V_{OUT})$	$V_{CE}=V_{IN}$, $I_{OUT}=10mA$ $-40^\circ C \leq T_a \leq 85^\circ C$	-	± 100	-	ppm/ $^\circ C$	①
Power Supply Rejection Ratio	PSRR	$V_{OUT(T)} < 2.5V$ $V_{IN}=3.0V_{DC}+0.5V_{p-pAC}$ $V_{CE}=V_{OUT(T)}+1.0V$ $I_{OUT}=30mA$, $f=1kHz$	-	80	-	dB	③
		$V_{OUT(T)} \geq 2.5V$ $V_{IN}=\{V_{OUT(T)}+1.0\}V_{DC}+0.5V_{p-pAC}$ $V_{CE}=V_{OUT(T)}+1.0V$ $I_{OUT}=30mA$, $f=1kHz$					
Current Limit	I_{LIM}	$V_{CE}=V_{IN}$	310	400	-	mA	①
Short Current	I_{SHORT}	$V_{CE}=V_{IN}$, $V_{OUT}=V_{SS}$	-	50	-	mA	①
CE High Level Voltage	V_{CEH}	-	1.0	-	5.5	V	④
CE Low Level Voltage	V_{CEL}	-	0	-	0.3	V	④
CE High Level Current	I_{CEH}	$V_{CE}=V_{IN}=5.5V$	3.0	5.5	9.0	μA	④
CE Low Level Current	I_{CEL}	$V_{CE}=V_{SS}$	-0.1	-	0.1	μA	④
C_L Discharge Resistance	R_{DCHG}	$V_{IN}=5.5V$, $V_{OUT}=2.0V$, $V_{CE}=V_{SS}$	-	300	-	Ω	①
Inrush Current (H Type)	I_{rush}	$V_{IN}=5.5V$, $V_{CE}=0 \rightarrow 5.5V$	-	150	-	mA	⑤
Thermal Shutdown Detect Temperature	T_{TSD}	Junction Temperature	-	150	-	$^\circ C$	①
Thermal Shutdown Release Temperature	T_{TSR}	Junction Temperature	-	120	-	$^\circ C$	
Thermal Shutdown Hysteresis Width	$T_{TSD} - T_{TSR}$	Junction Temperature	-	30	-	$^\circ C$	

NOTE:

Unless otherwise stated regarding input voltage conditions, $V_{IN}=V_{OUT(T)}+1.0V$.

(*1) $V_{OUT(E)}$: Effective output voltage

(i.e. the output voltage when " $V_{OUT(T)}+1.0V$ " is provided at the V_{IN} pin while maintaining a certain I_{OUT} value.)

(*2) $V_{OUT(T)}$: Nominal output voltage

(*3) The standard output voltage is specified in $V_{OUT(T)} \pm 20mV$ where $V_{OUT(T)} < 2.0V$.

(*4) $V_{dif}=V_{IN1}-V_{OUT1}$ ($V_{IN1} \geq 1.6V$)

V_{IN1} =The input voltage when V_{OUT1} appears as input voltage is gradually decreased.

V_{OUT1} =A voltage equal to 98% of the output voltage whenever an amply stabilized $V_{OUT(T)}+1.0V$ is input for every I_{OUT} .

■ OUTPUT VOLTAGE CHART

● Voltage Chart 1

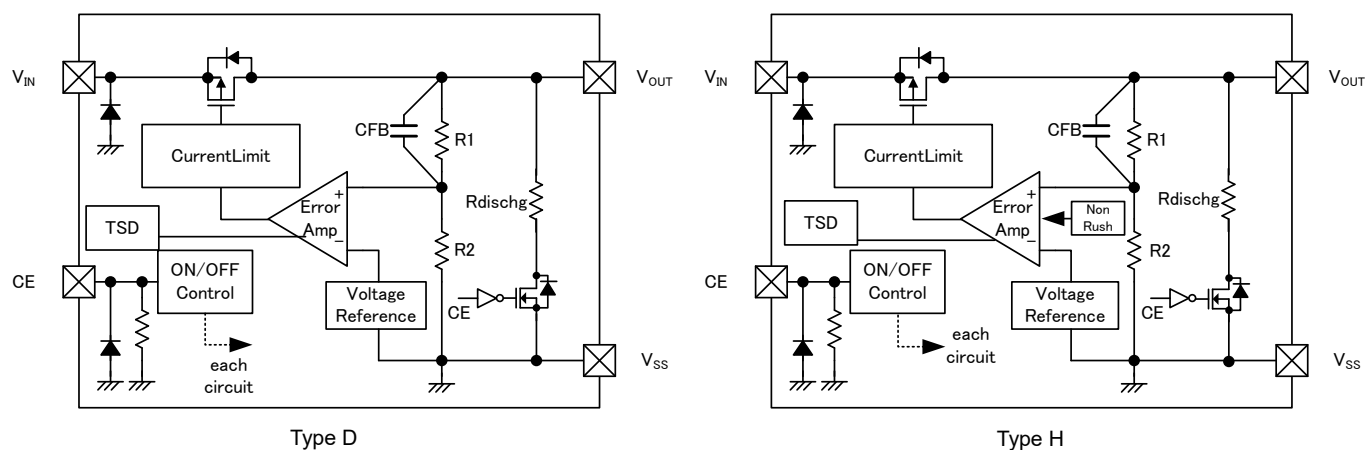
NOMINAL OUTPUT VOLTAGE (V)	OUTPUT VOLTAGE (V)		DROPOUT VOLTAGE (mV) E-1	
V _{OUT(T)}	V _{OUT(E)}		V _{dif}	
	MIN.	MAX.	TYP.	MAX.
1.20	1.1800	1.2200	470	625
1.25	1.2300	1.2700		
1.30	1.2800	1.3200		
1.35	1.3300	1.3700	420	575
1.40	1.3800	1.4200		
1.45	1.4300	1.4700		
1.50	1.4800	1.5200	380	505
1.55	1.5300	1.5700		
1.60	1.5800	1.6200		
1.65	1.6300	1.6700	350	455
1.70	1.6800	1.7200		
1.75	1.7300	1.7700		
1.80	1.7800	1.8200	320	440
1.85	1.8300	1.8700		
1.90	1.8800	1.9200		
1.95	1.9300	1.9700	260	380
2.00	1.9800	2.0200		
2.05	2.0295	2.0705		
2.10	2.0790	2.1210	230	340
2.15	2.1285	2.1715		
2.20	2.1780	2.2220		
2.25	2.2275	2.2725		
2.30	2.2770	2.3230		
2.35	2.3265	2.3735		
2.40	2.3760	2.4240		
2.45	2.4255	2.4745		
2.50	2.4750	2.5250	190	300
2.55	2.5245	2.5755		
2.60	2.5740	2.6260		
2.65	2.6235	2.6765		
2.70	2.6730	2.7270		
2.75	2.7225	2.7775		
2.80	2.7720	2.8280		
2.85	2.8215	2.8785		
2.90	2.8710	2.9290		
2.95	2.9205	2.9795		

■ OUTPUT VOLTAGE CHART (Continued)

● Voltage Chart 2

NOMINAL OUTPUT VOLTAGE (V)	OUTPUT VOLTAGE (V)		DROPOUT VOLTAGE (mV) E-1	
V _{OUT(T)}	V _{OUT(E)}		V _{dif}	
	MIN.	MAX.	TYP.	MAX.
3.00	2.9700	3.0300	160	260
3.05	3.0195	3.0805		
3.10	3.0690	3.1310		
3.15	3.1185	3.1815		
3.20	3.1680	3.2320		
3.25	3.2175	3.2825		
3.30	3.2670	3.3330		
3.35	3.3165	3.3835		
3.40	3.3660	3.4340		
3.45	3.4155	3.4845		
3.50	3.4650	3.5350		
3.55	3.5145	3.5855		
3.60	3.5640	3.6360		
3.65	3.6135	3.6865		
3.70	3.6630	3.7370		
3.75	3.7125	3.7875		
3.80	3.7620	3.8380		
3.85	3.8115	3.8885		
3.90	3.8610	3.9390		
3.95	3.9105	3.9895		
4.00	3.9600	4.0400		

■ OPERATIONAL EXPLANATION



The voltage divided by resistors $R1$ & $R2$ is compared with the internal reference voltage by the error amplifier. The P-channel MOSFET which is connected to the V_{OUT} pin is then driven by the subsequent output signal. The output voltage at the V_{OUT} pin is controlled and stabilized by a system of negative feedback. The current limit circuit and short circuit protection operate in relation to the level of output current and heat dissipation. Further, the IC's internal circuitry can be shutdown via the CE pin signal.

<Low ESR Capacitor>

The XC6229 series needs an output capacitor C_L for phase compensation. Please place an output capacitor (C_L) at the output pin (V_{OUT}) and the ground pin (V_{SS}) as close as possible. Please use the output capacitor (C_L) is $1.0\mu F$ or larger. For a stable power input, please connect an input capacitor (C_{IN}) of $1.0\mu F$ between the V_{IN} pin and the V_{SS} pin.

<Current Limiter, Short-Circuit Protection>

The protection circuit operates as a combination of an output current limiter and fold-back short circuit protection. When load current reaches the current limit level, the output voltage drops. As a result, the load current starts to reduce with showing fold-back curve. When the output is short-circuited, the current drops to the Short Current (I_{short}).

<CE Pin>

The IC's internal circuitry can be shutdown via the signal from the CE pin. In shutdown mode, the XC6229 series enables the electric charge at the output capacitor (C_L) to be discharged via the internal switch located between the V_{OUT} and V_{SS} pins, and as a result the V_{OUT} pin quickly returns to the V_{SS} level. The XC6229 series has a pull-down resistor at the CE pin inside, so that the CE pin input current flows.

■ OPERATIONAL EXPLANATION

<Thermal Shutdown>

When the junction temperature of the built-in driver transistor reaches the temperature limit, the thermal shutdown circuit operates and the driver transistor will be set to OFF. The IC resumes its operation when the thermal shutdown function is released and the IC's operation is automatically restored because the junction temperature drops to the level of the thermal shutdown release voltage.

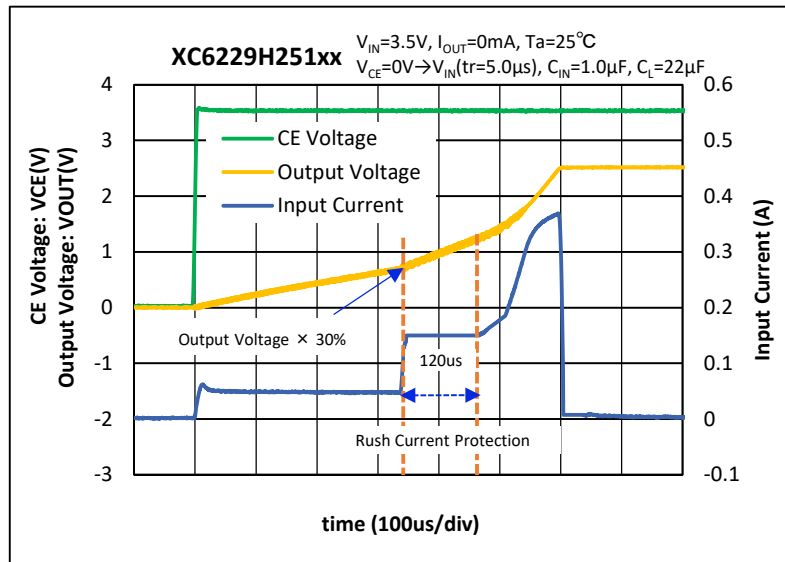
<Inrush Current Protection>

The inrush current protection circuit is built in the XC6229 type H.

When the output voltage is about 30% or less of the set voltage after the IC starts up, a short-circuit current flows and the output voltage rises. When the output voltage reaches about 30% of the set voltage, the inrush current prevention function operates for a period of about 120 μ s.

While the inrush current prevention function is operating, the inrush current flowing from the input pin(V_{IN}) to the output pin(V_{OUT}) is suppressed not to exceed the Irush (150mA TYP.).

After the inrush current prevention function is released, the current flowing from the input pin to the output pin is limited by the current limit circuit.

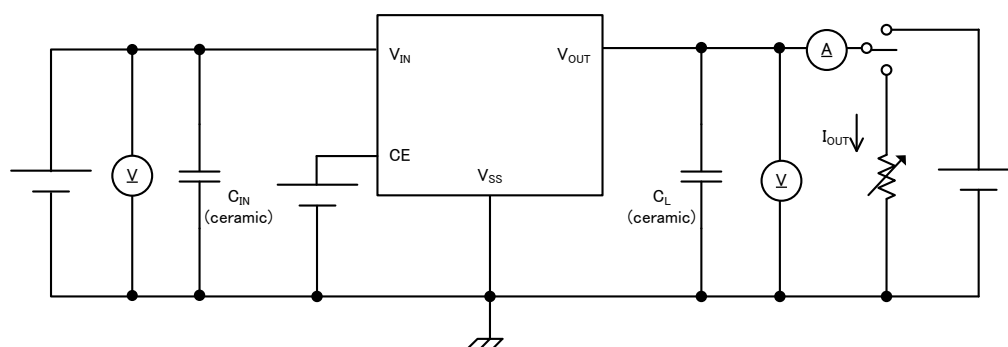


■ NOTES ON USE

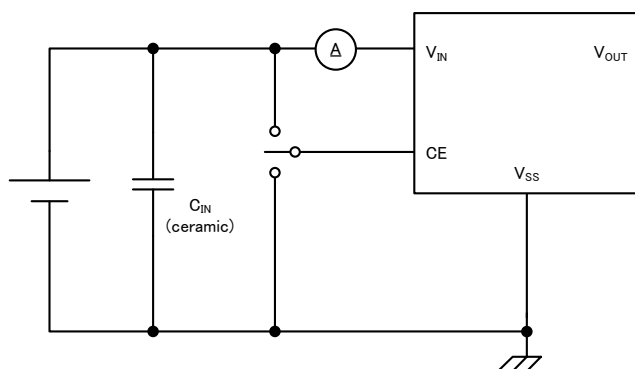
1. For temporary, transitional voltage drop or voltage rising phenomenon, the IC is liable to malfunction should the ratings be exceeded.
2. Where wiring impedance is high, operations may become unstable due to the noise and/or phase lag depending on output current. Please strengthen V_{IN} and V_{SS} wiring in particular.
3. The input capacitor C_{IN} and the output capacitor C_L should be placed to the as close as possible with a shorter wiring.
4. The type H is controlled with constant current start-up. Start-up sequence control is requested to draw a load current after the output voltage is raised up to around the internally fixed nominal output voltage.
5. Torex places an importance on improving our products and its reliability.
However, by any possibility, we would request user fail-safe design and post-aging treatment on system or equipment.

■ TEST CIRCUITS

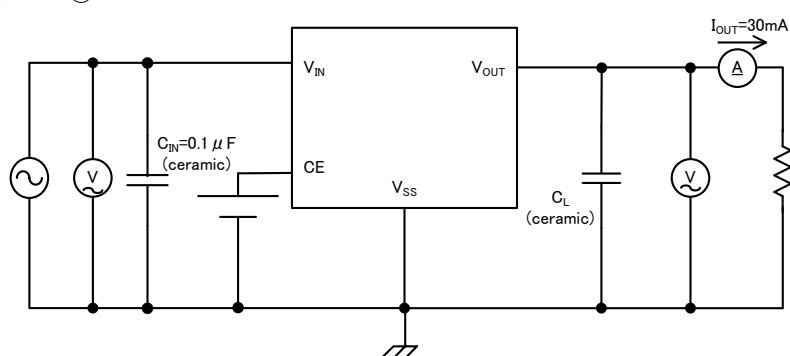
● Circuit ①



● Circuit ②

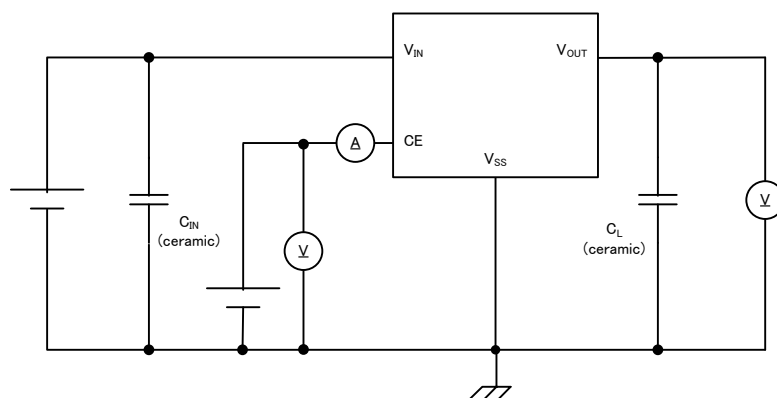


● Circuit ③

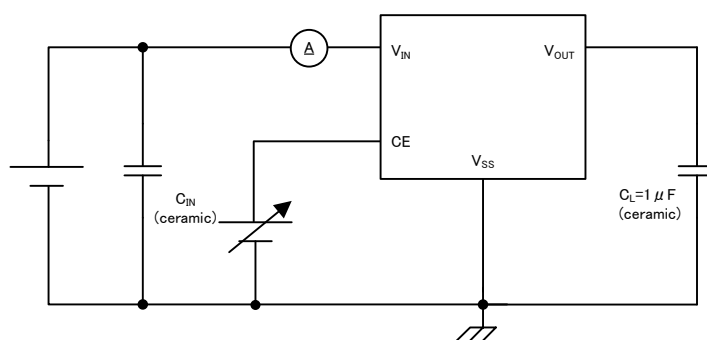


TEST CIRCUITS (Continued)

● Circuit ④



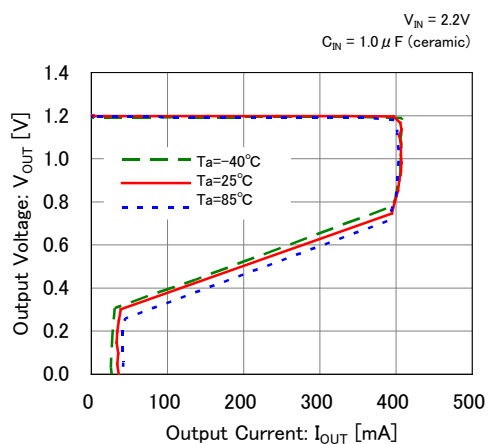
● Circuit ⑤



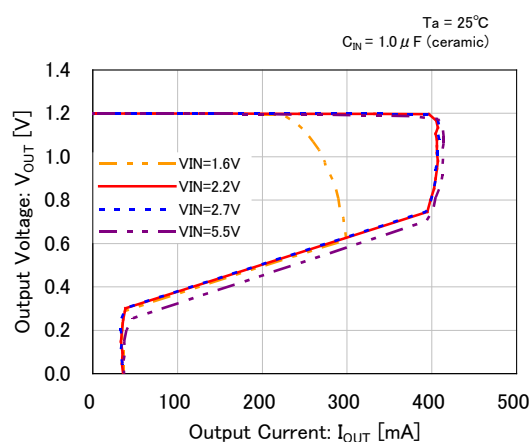
TYPICAL PERFORMANCE CHARACTERISTICS

(1) Output Voltage vs. Output Current

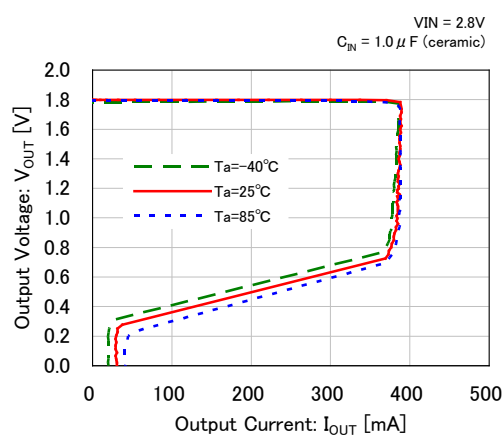
XC6229x121



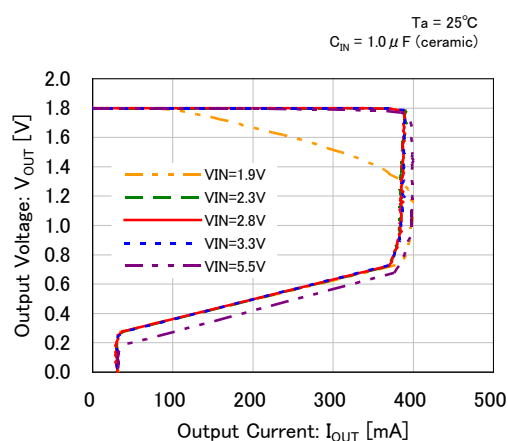
XC6229x121



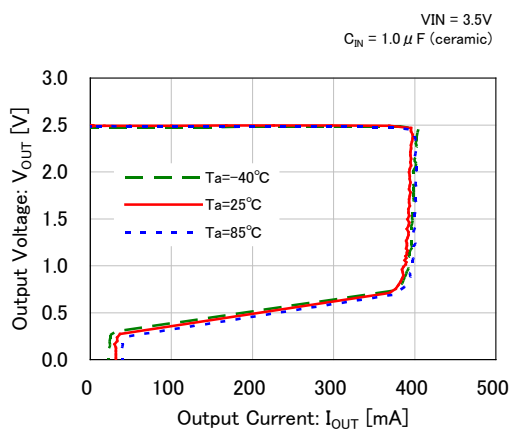
XC6229x181



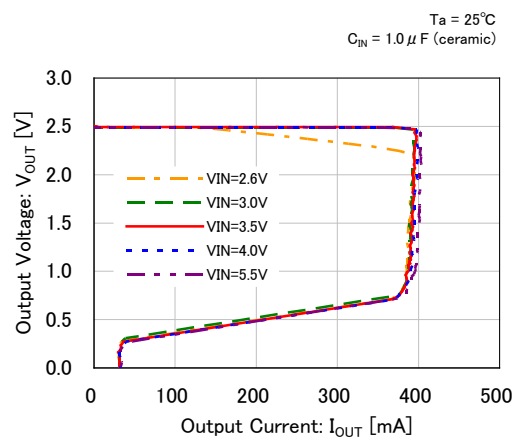
XC6229x181



XC6229x251

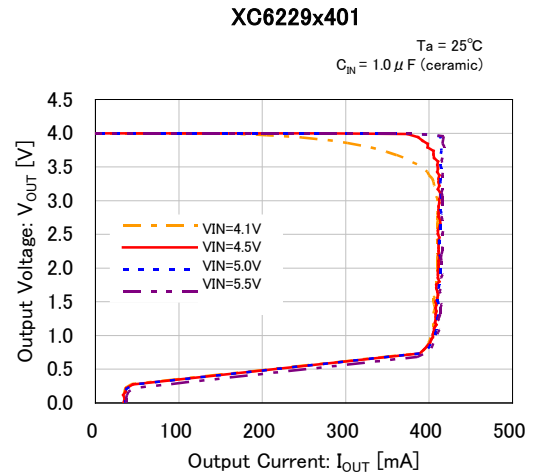
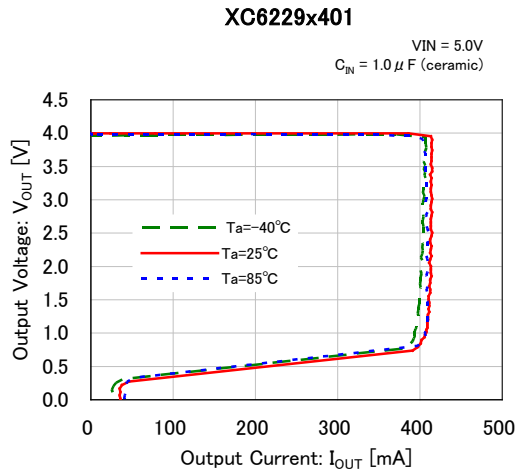


XC6229x251

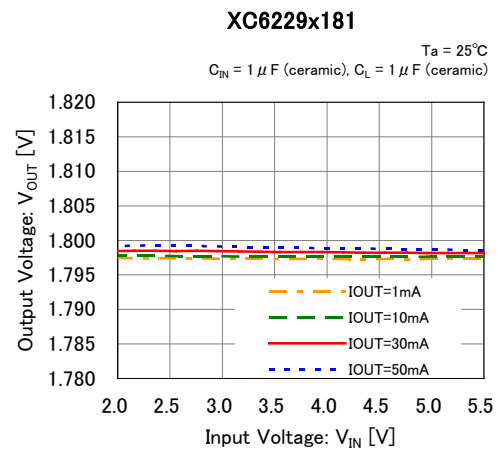
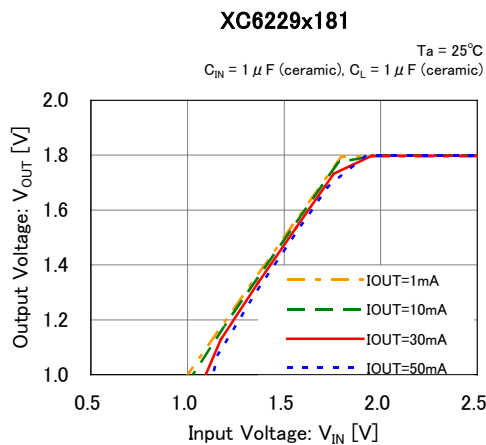
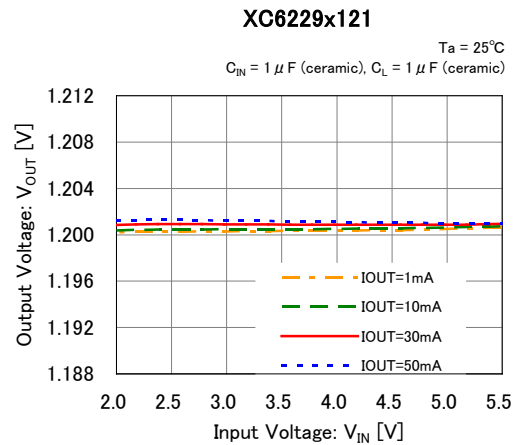
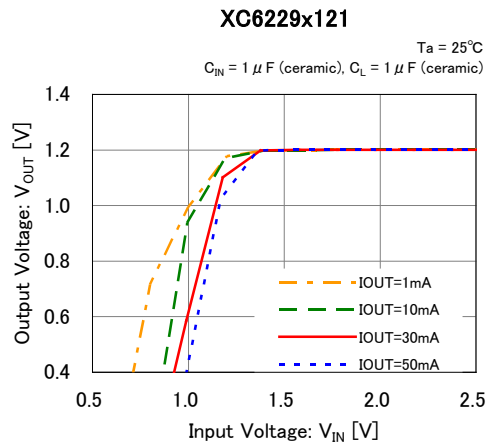


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(1) Output Voltage vs. Output Current (Continued)

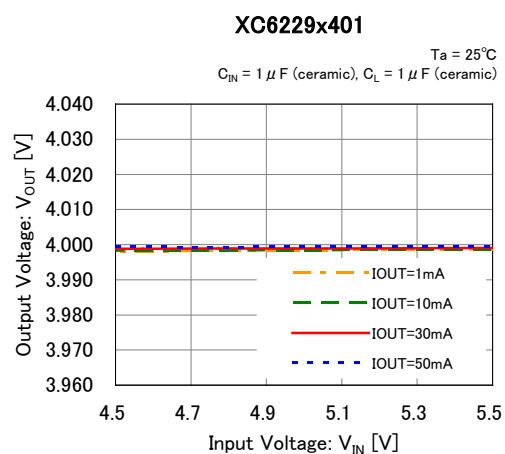
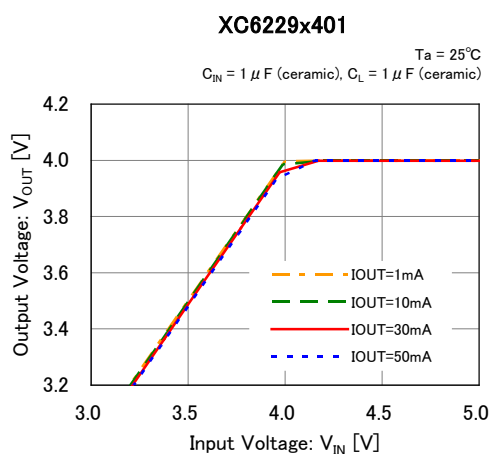
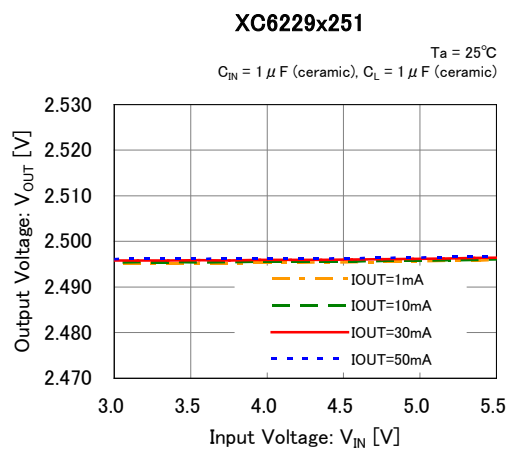
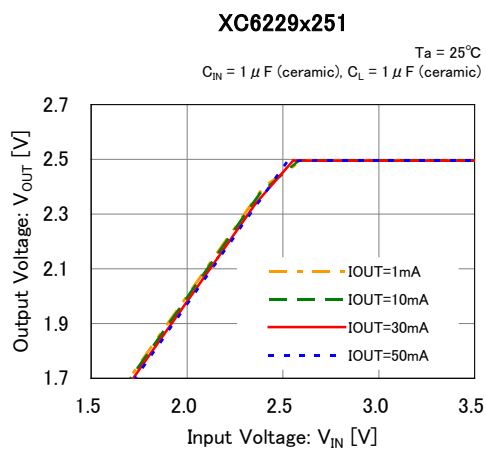


(2) Output Voltage vs. Input Voltage

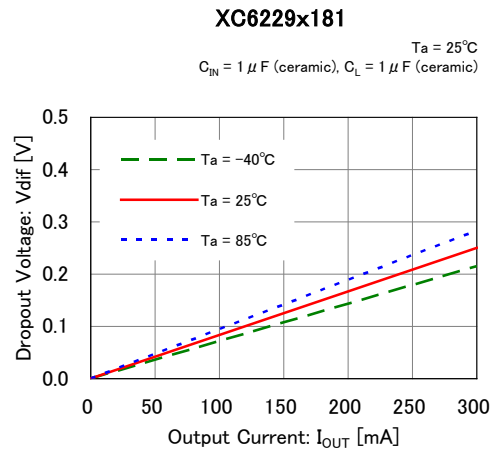
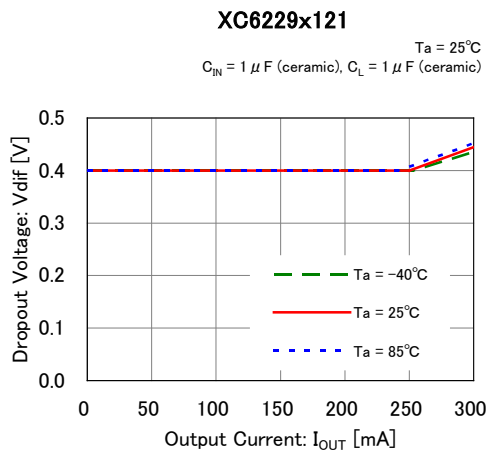


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(2) Output Voltage vs. Input Voltage (Continued)



(3) Dropout Voltage vs. Output Current

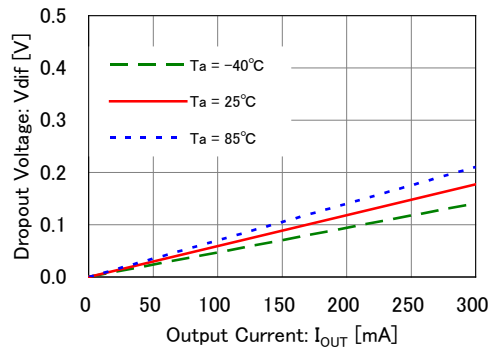


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(3) Dropout Voltage vs. Output Current (Continued)

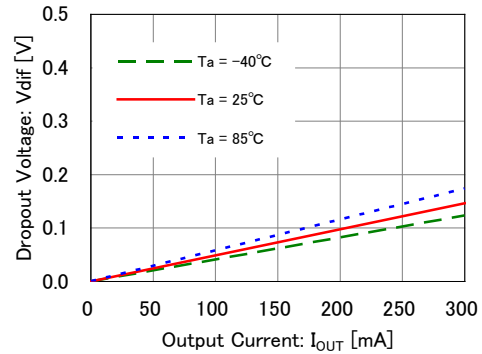
XC6229x251

$T_a = 25^\circ\text{C}$
 $C_{IN} = 1\ \mu\text{F}$ (ceramic), $C_L = 1\ \mu\text{F}$ (ceramic)



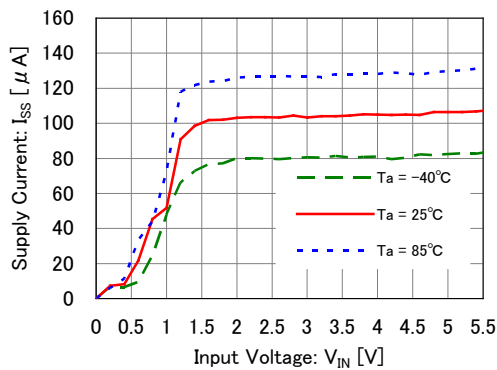
XC6229x401

$T_a = 25^\circ\text{C}$
 $C_{IN} = 1\ \mu\text{F}$ (ceramic), $C_L = 1\ \mu\text{F}$ (ceramic)

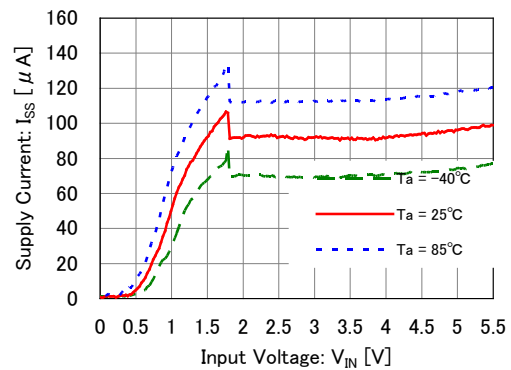


(4) Supply Current vs. Input Voltage

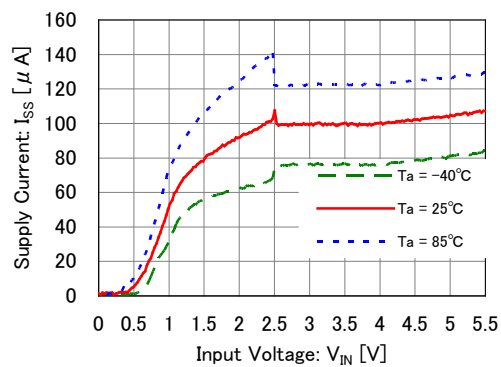
XC6229x121



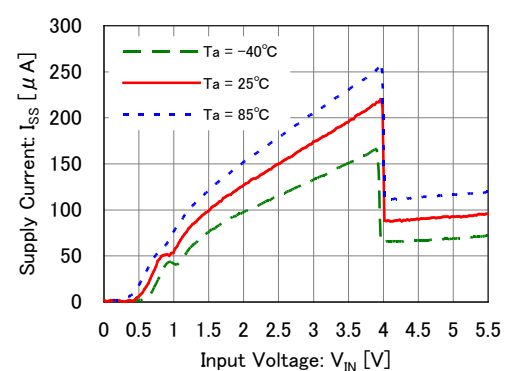
XC6229x181



XC6229x251

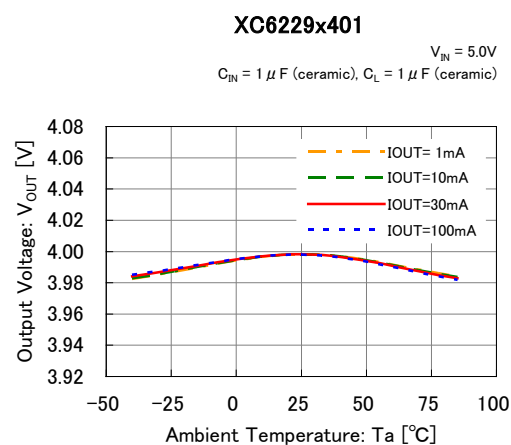
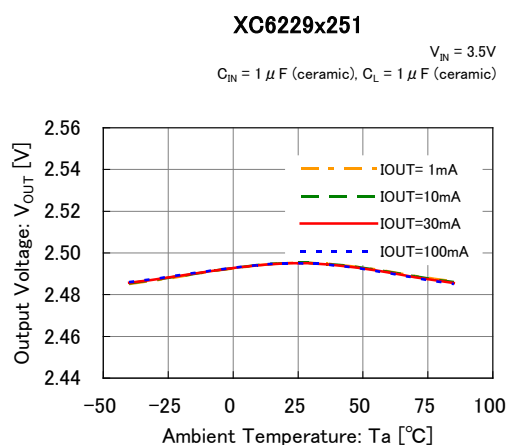
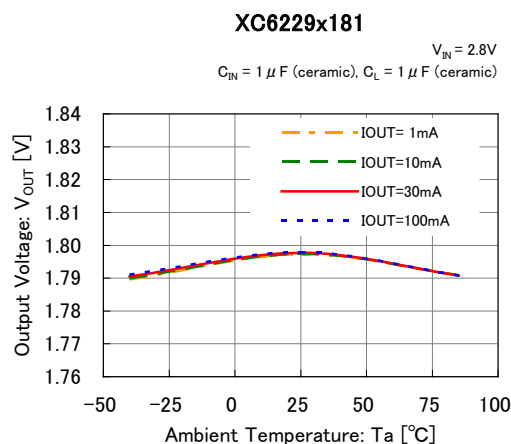
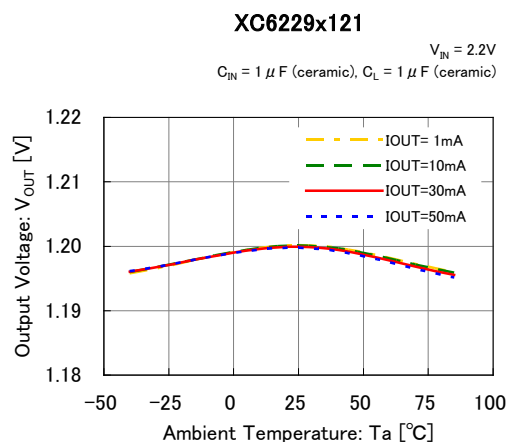


XC6229x401

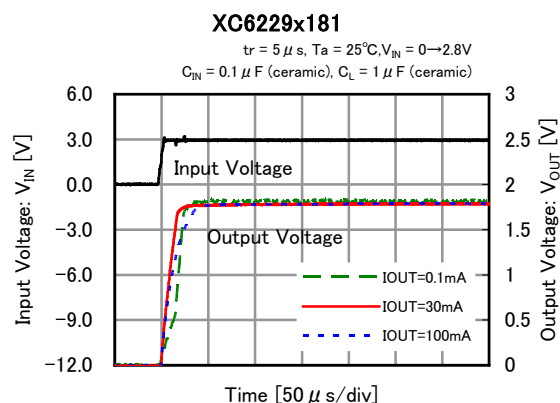
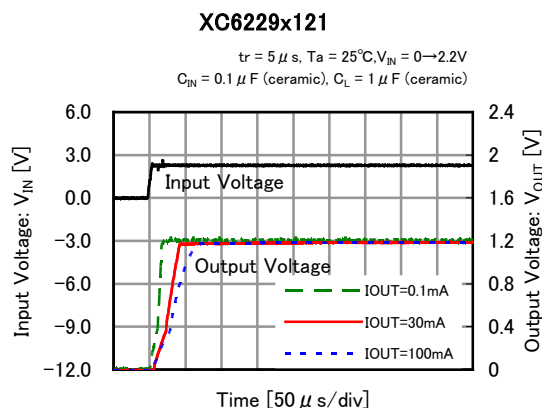


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(5) Output Voltage vs. Ambient Temperature



(6) Rising Response Time

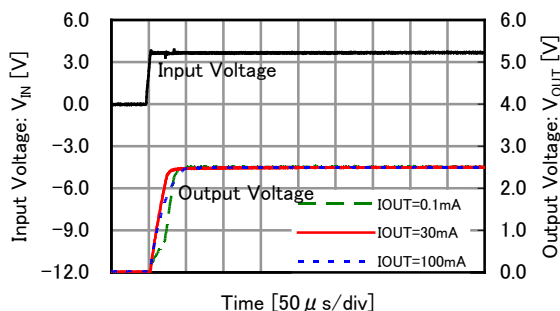


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(6) Rising Response Time (Continued)

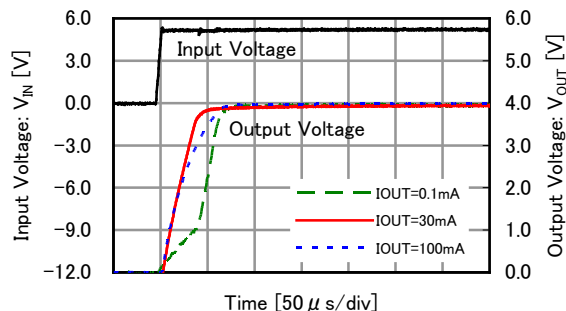
XC6229x251

$t_r = 5 \mu s$, $T_a = 25^\circ C$, $V_{IN} = 0 \rightarrow 3.5V$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



XC6229x401

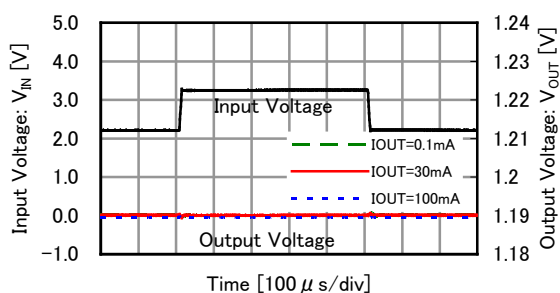
$t_r = 5 \mu s$, $T_a = 25^\circ C$, $V_{IN} = 0 \rightarrow 5.0V$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1 \mu F$ (ceramic)



(7) Input Transient Response

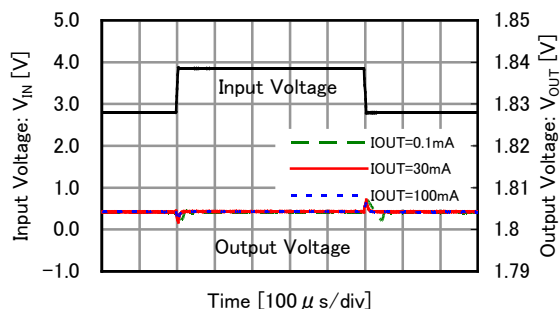
XC6229x121

$t_r = t_f = 5 \mu s$, $T_a = 25^\circ C$, $V_{IN} = 2.2V \leftrightarrow 3.2V$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1.0 \mu F$ (ceramic)



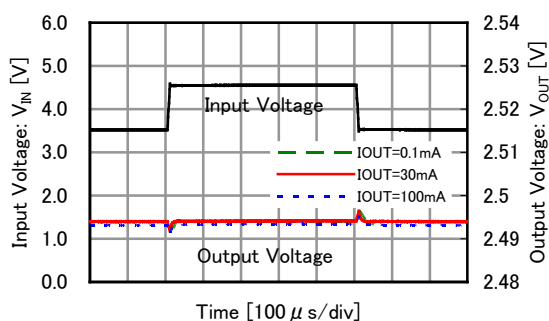
XC6229x181

$t_r = t_f = 5 \mu s$, $T_a = 25^\circ C$, $V_{IN} = 2.8V \leftrightarrow 3.8V$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1.0 \mu F$ (ceramic)



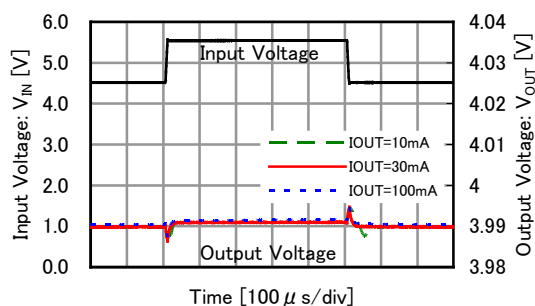
XC6229x251

$t_r = t_f = 5 \mu s$, $T_a = 25^\circ C$, $V_{IN} = 3.5V \leftrightarrow 4.5V$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1.0 \mu F$ (ceramic)



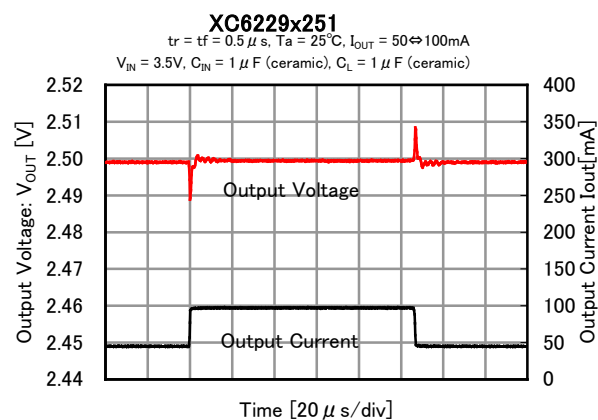
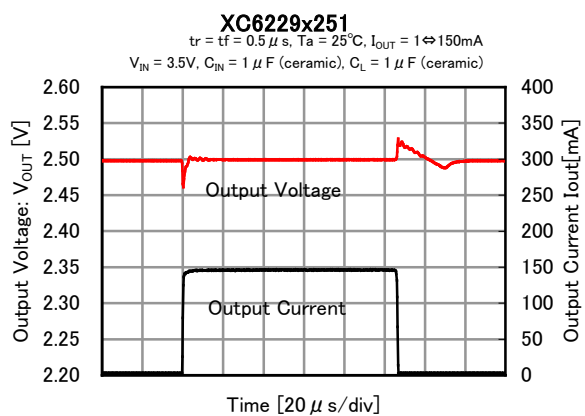
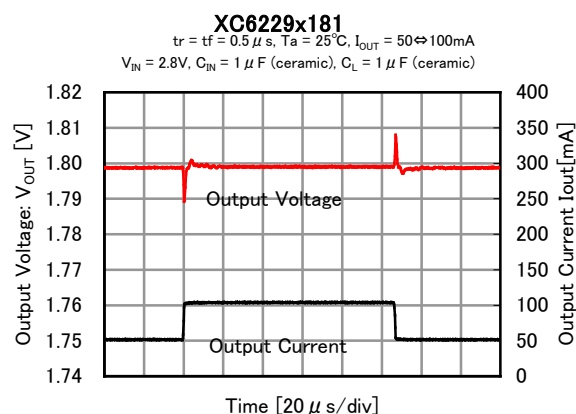
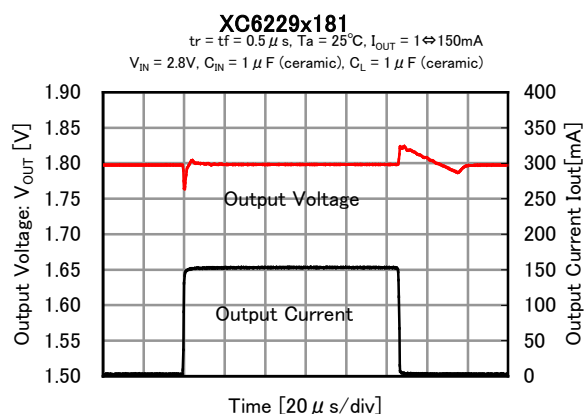
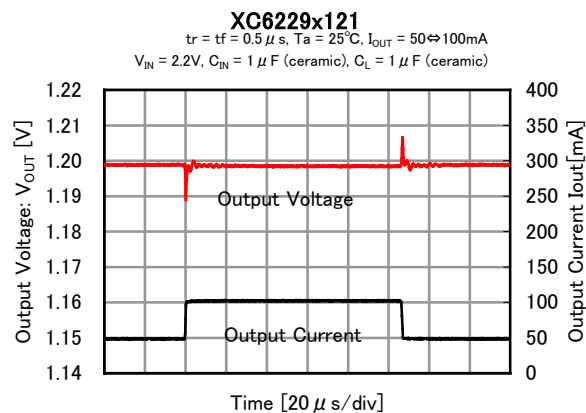
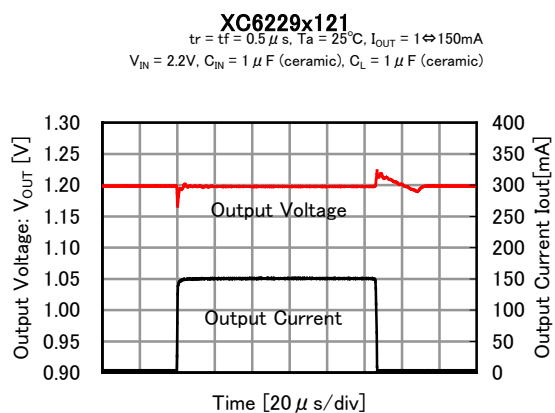
XC6229x401

$t_r = t_f = 5 \mu s$, $T_a = 25^\circ C$, $V_{IN} = 4.5V \leftrightarrow 5.5V$
 $C_{IN} = 0.1 \mu F$ (ceramic), $C_L = 1.0 \mu F$ (ceramic)



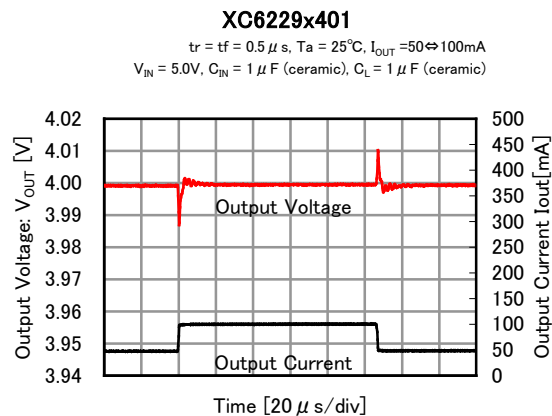
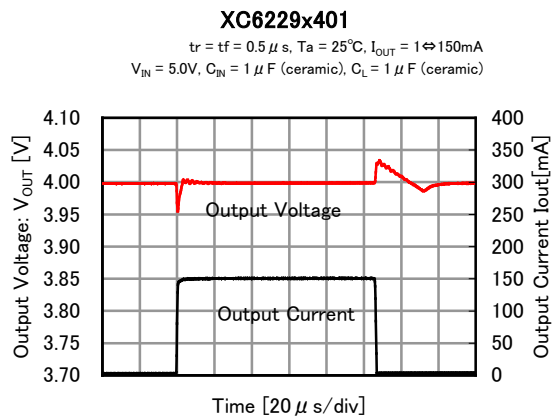
■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(8) Load Transient Response ($t_r=t_f=0.5\mu s$)

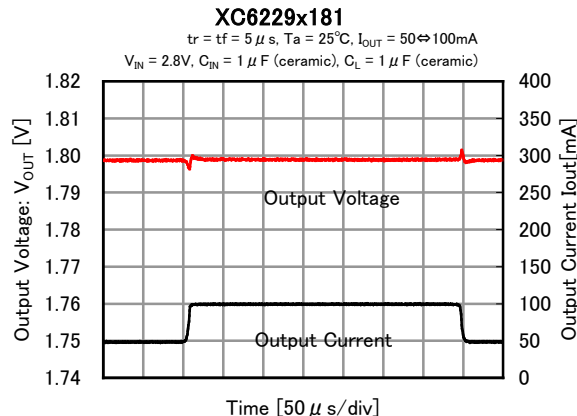
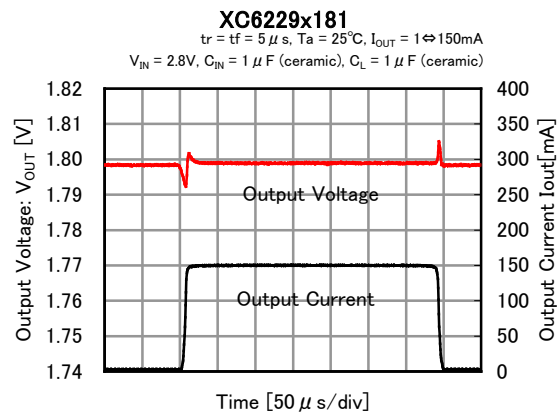
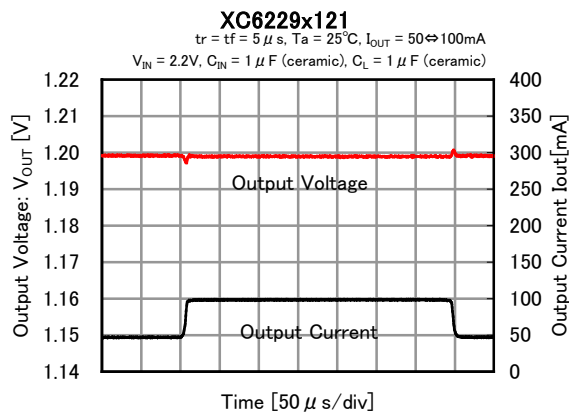
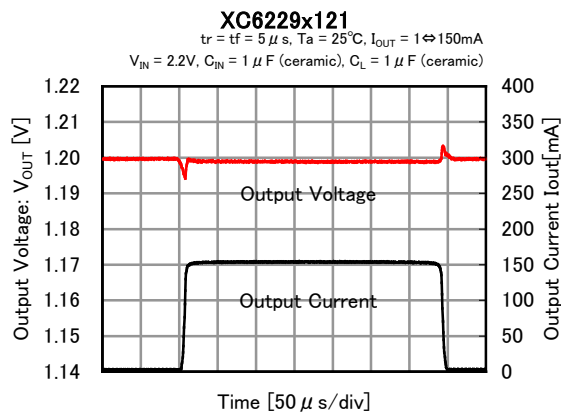


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(8) Load Transient Response ($t_r=t_f=0.5\mu s$) (Continued)

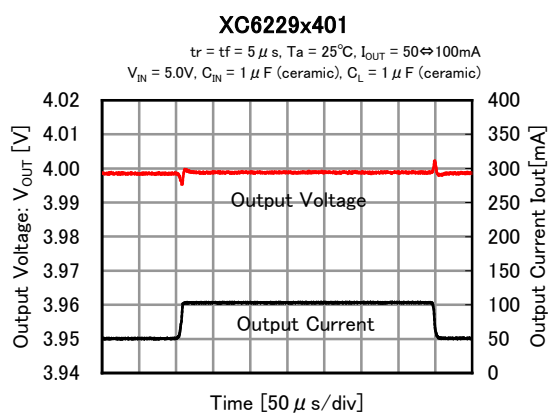
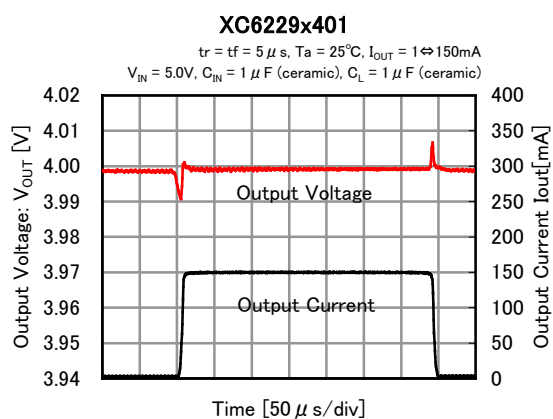
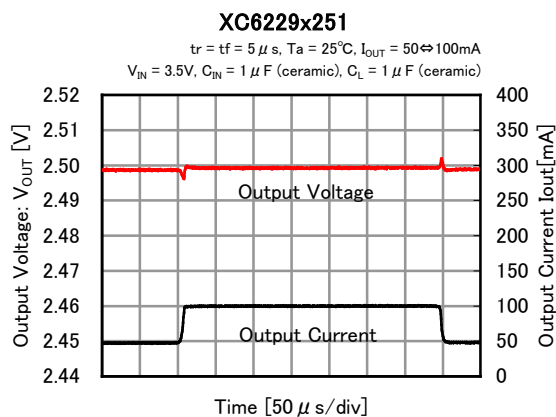
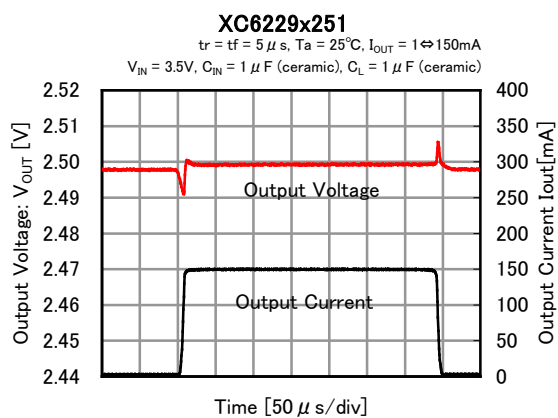


(8) Load Transient Response ($t_r=t_f=5\mu s$) (Continued)

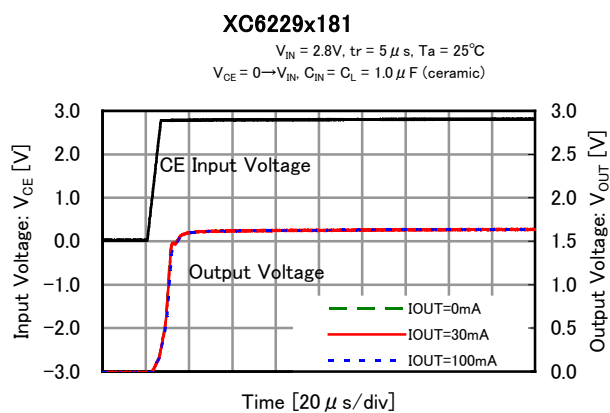
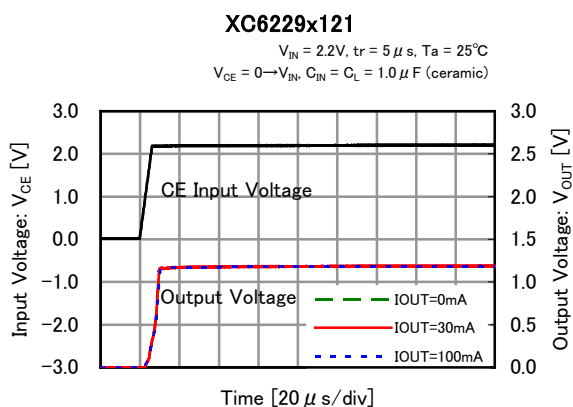


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(8) Load Transient Response ($t_r=t_f=5\mu s$) (Continued)

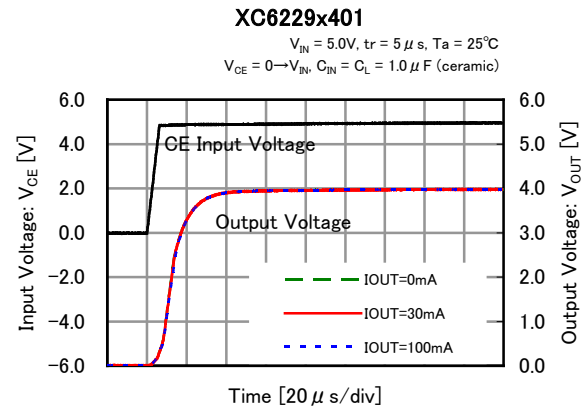
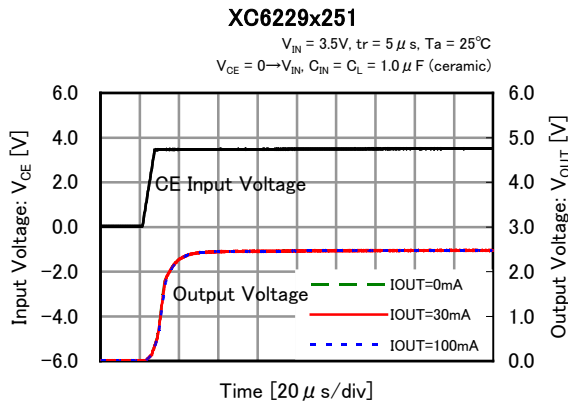


(9) CE Rising Response Time (Type D)

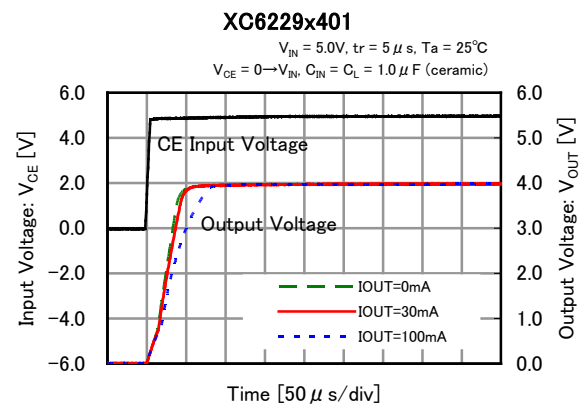
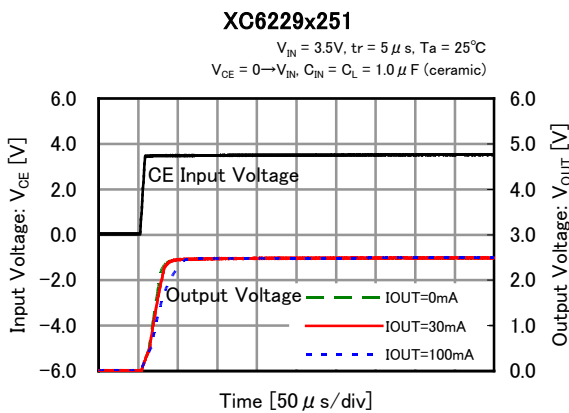
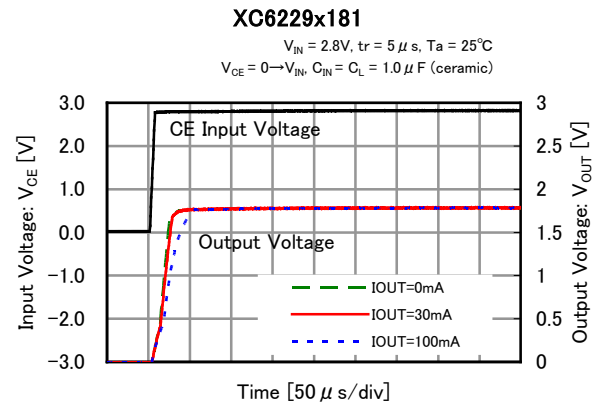
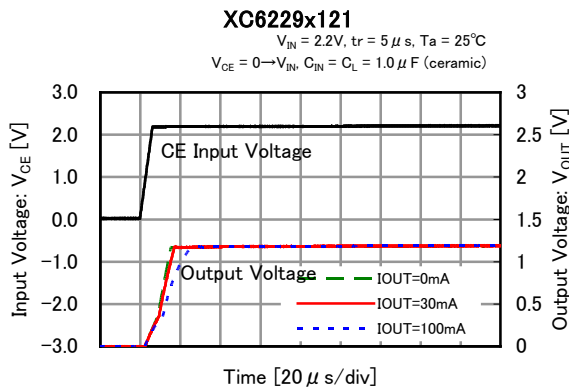


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(9) CE Rising Response Time (Type D) (Continued)



(9) CE Rising Response Time (Type H) (Continued)

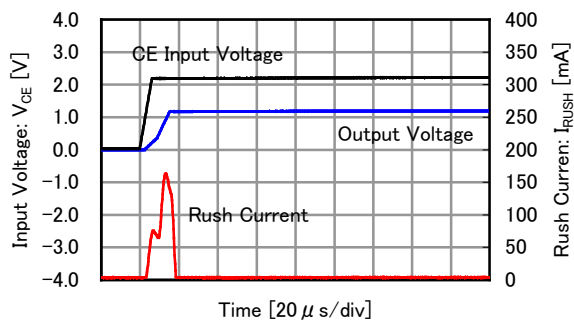


■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(10) Inrush Current Response Time (Type H)

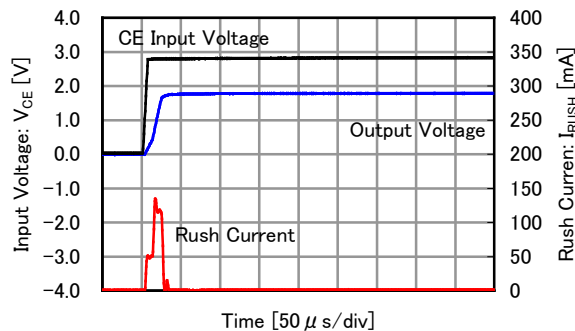
XC6229x121

$V_{IN} = 2.2V$, $t_r = 5 \mu s$, $T_a = 25^\circ C$
 $V_{CE} = 0 \rightarrow V_{IN}$, $C_{IN} = C_L = 1.0 \mu F$ (ceramic)



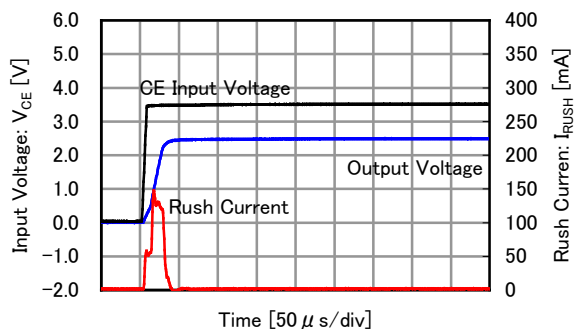
XC6229x181

$V_{IN} = 2.8V$, $t_r = 5 \mu s$, $T_a = 25^\circ C$
 $V_{CE} = 0 \rightarrow V_{IN}$, $C_{IN} = C_L = 1.0 \mu F$ (ceramic)



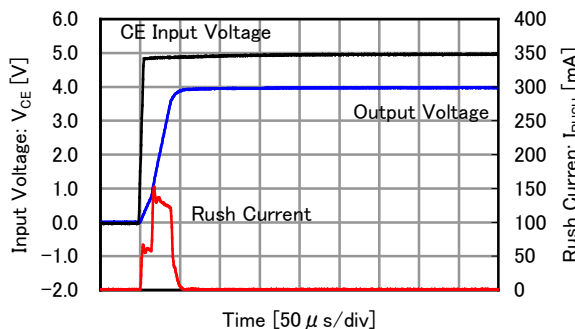
XC6229x251

$V_{IN} = 3.5V$, $t_r = 5 \mu s$, $T_a = 25^\circ C$
 $V_{CE} = 0 \rightarrow V_{IN}$, $C_{IN} = C_L = 1.0 \mu F$ (ceramic)



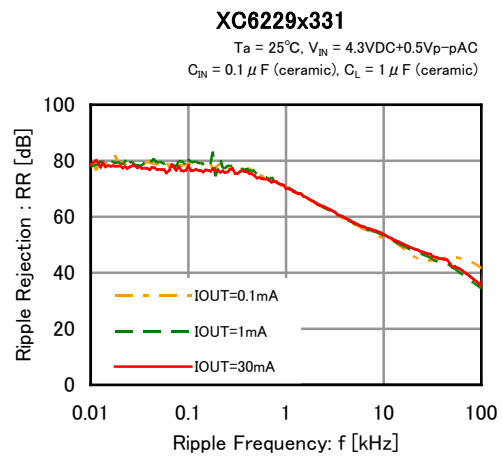
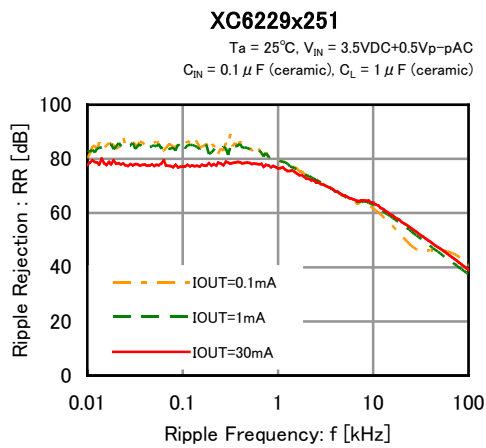
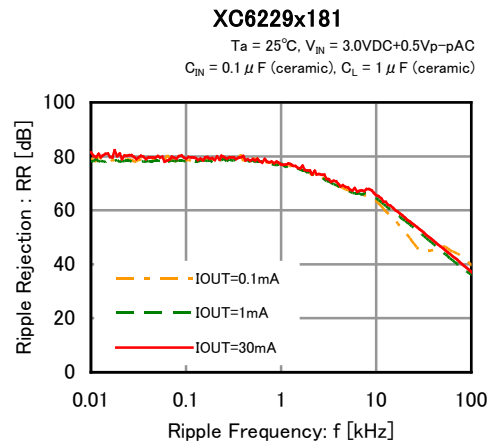
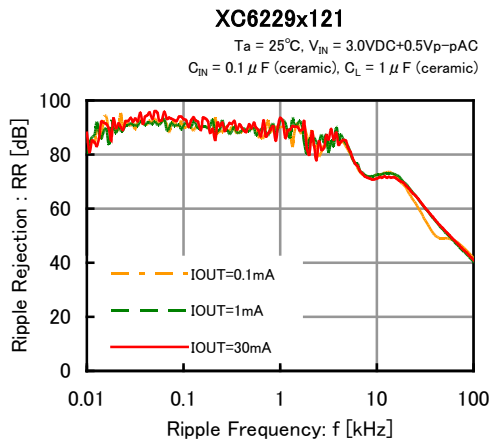
XC6229x401

$V_{IN} = 5.0V$, $t_r = 5 \mu s$, $T_a = 25^\circ C$
 $V_{CE} = 0 \rightarrow V_{IN}$, $C_{IN} = C_L = 1.0 \mu F$ (ceramic)

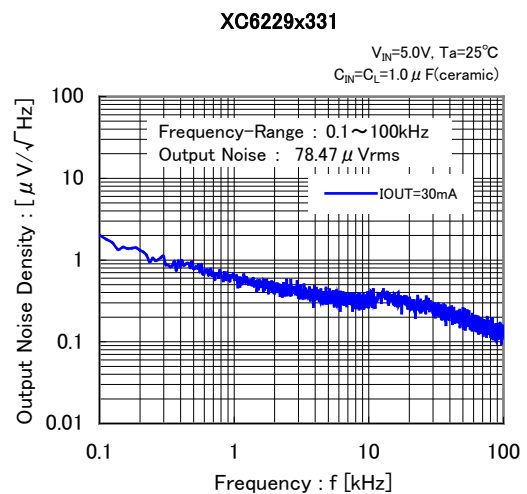
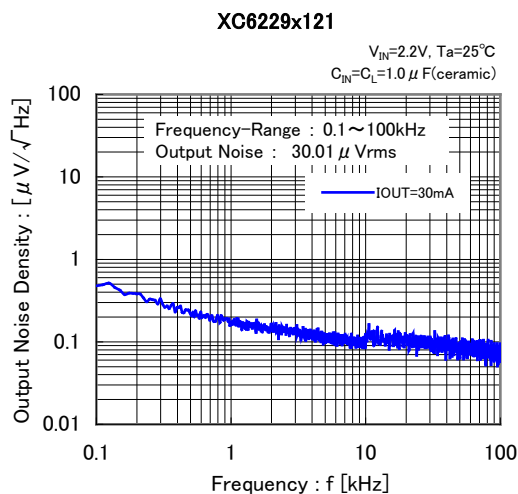


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(11) Ripple Rejection Rate



(12) Output Noise Density



■ PACKAGING INFORMATION

For the latest package information go to, www.torexsemi.com/technical-support/packages

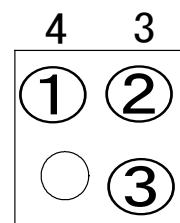
PACKAGE	OUTLINE / LAND PATTERN	THERMAL CHARACTERISTICS
LGA-4B01	LGA-4B01 PKG	LGA-4B01 Power Dissipation

MARKING RULE

●LGA-4B01

① represents type of regulator and output voltage range.

MARK	TYPE	VOLTAGE RANGE	PRODUCT SERIES
0	D	1.2~2.6	XC6229D1211*-G ~ XC6229D2611*-G
1		2.65~4.0	XC6229D26B1*-G ~ XC6229D4011*-G
2	H	1.2~2.6	XC6229H1211*-G ~ XC6229H2611*-G
3		2.65~4.0	XC6229H26B1*-G ~ XC6229H4011*-G



LGA-4B01
(TOP VIEW)

② represents output voltage.

MARK	OUTPUT VOLTAGE (V)		MARK	OUTPUT VOLTAGE (V)		MARK	OUTPUT VOLTAGE (V)	
0	1.2	2.65	A	1.7	3.15	N	2.2	3.65
1	1.25	2.7	B	1.75	3.2	P	2.25	3.7
2	1.3	2.75	C	1.8	3.25	R	2.3	3.75
3	1.35	2.8	D	1.85	3.3	S	2.35	3.8
4	1.4	2.85	E	1.9	3.35	T	2.4	3.85
5	1.45	2.9	F	1.95	3.4	U	2.45	3.9
6	1.5	2.95	H	2.0	3.45	V	2.5	3.95
7	1.55	3.0	K	2.05	3.5	X	2.55	4.0
8	1.6	3.05	L	2.1	3.55	Y	2.6	
9	1.65	3.1	M	2.15	3.6			

③ represents production lot number.

0~9, A~Z in order.

(G, I, J, O, Q, W excepted)

*No character inversion used.

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